DATA SHEET

74LVT623

3.3 V octal transceiver with dual enable (3-State)

Product specification
Supersedes data of 1996 Feb 15
IC24 Data Handbook

1999 Jul 09

Philips
Semiconductors

PHILIPS

3.3 V octal transceiver with dual enable (3-State) 74LVT623

FEATURES

- Separate controls for data flow in each direction
- Output capability: +64 mA/–32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5 V bus
- Power-up 3-State
- Power-up reset
- Latch-up protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74LVT623 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

The 74LVT623 device is an octal transceiver featuring non–inverting 3-State bus compatible outputs in both send and receive directions. The 74LVT623 is designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing. This device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the Enable inputs ($\overline{OEBA}$ and OEAB). The Enable inputs can be used to disable the device so that the buses are effectively isolated.

Control of data flow from B to A is similar, but using the $\overline{EBA}$, $\overline{LEBA}$, and $\overline{OEBA}$ inputs.

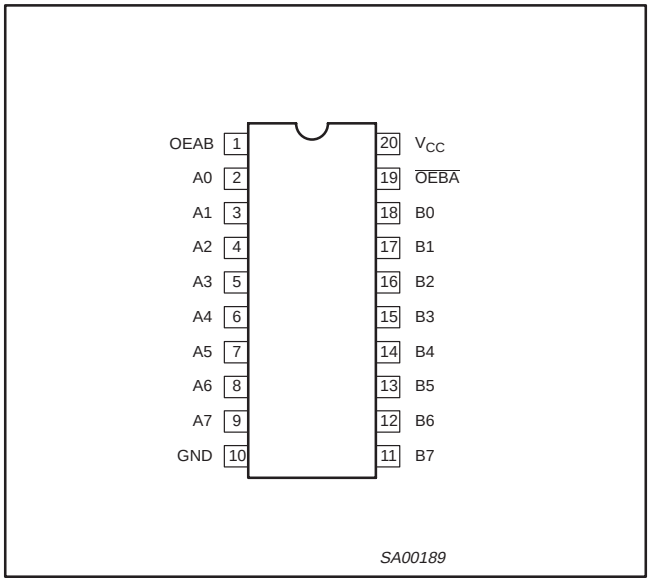
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T_{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An to Bn or Bn to An	C_L = 50pF; V_{CC} = 3.3 V	2.3 2.5	ns
C_{IN}	Input capacitance	V_I = 0 V or 3.0 V	4	pF
$C_{I/O}$	I/O capacitance	Outputs disabled; $V_{I/O}$ = 0 V or 3.0 V	7	pF
I_{CCZ}	Total supply current	Outputs disabled; V_{CC} = 3.6 V	0.13	mA

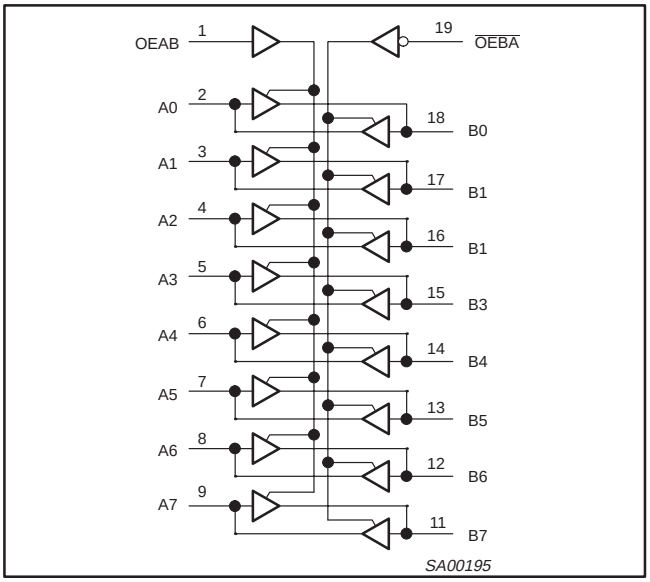
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
24-Pin Plastic SOL	–40°C to +85°C	74LVT623 D	74LVT623 D	SOT137-1
24-Pin Plastic SSOP Type II	–40°C to +85°C	74LVT623 DB	74LVT623 DB	SOT340-1
24-Pin Plastic TSSOP Type I	–40°C to +85°C	74LVT623 PW	74LVT623PW DH	SOT355-1

PIN CONFIGURATION

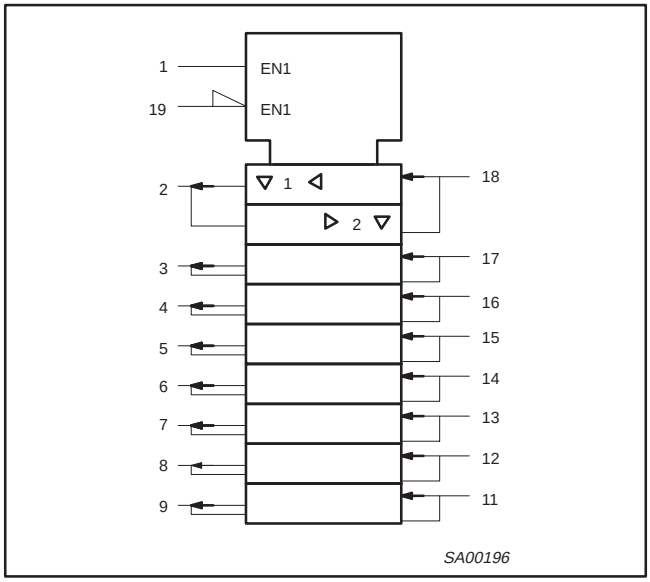


LOGIC SYMBOL



3.3 V octal transceiver with dual enable (3-State) 74LVT623

LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	OEAB	Output enable input, A side to B side (active-High)
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	$\overline{OEBA}$	Output enable input, B side to A side (active-Low)
10	GND	Ground (0 V)
20	V_{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		INPUTS/OUTPUTS	
$\overline{OEBA}$	OEAB	An	Bn
L	L	An = Bn	Inputs
H	H	Inputs	Bn = An
H	L	Z	Z
L	H	An = Bn	Bn = An

H = High voltage level
L = Low voltage level
Z = High impedance “off” state

ABSOLUTE MAXIMUM RATINGS[1, 2]

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		–0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	–50	mA
V_I	DC input voltage[3]		–0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	–50	mA
V_{OUT}	DC output voltage[3]	Output in Off or High state	–0.5 to +7.0	V
I_{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	–64	
T_{stg}	Storage temperature range		–65 to 150	°C

NOTES:
1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I_{OH}	High-level output current		–32	mA
I_{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1 kHz		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	–40	+85	°C

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS Temp = -40°C to +85°C			UNIT
				MIN	TYP[1]	MAX	
V_{IK}	Input clamp voltage	V_{CC} = 2.7 V; I_{IK} = –18 mA			–0.9	–1.2	V
V_{OH}	High-level output voltage	V_{CC} = 2.7 to 3.6 V; I_{OH} = –100 µA		V_{CC}-0.2	V_{CC}-0.1		V
		V_{CC} = 2.7 V; I_{OH} = –8 mA		2.4	2.5		
		V_{CC} = 3.0 V; I_{OH} = –32 mA		2.0	2.2		
V_{OL}	Low-level output voltage	V_{CC} = 2.7 V; I_{OL} = 100 µA			0.1	0.2	V
		V_{CC} = 2.7 V; I_{OL} = 24 mA			0.3	0.5	
		V_{CC} = 3.0 V; I_{OL} = 16 mA			0.25	0.4	
		V_{CC} = 3.0 V; I_{OL} = 32 mA			0.3	0.5	
		V_{CC} = 3.0 V; I_{OL} = 64 mA			0.4	0.55	
V_{RST}	Power-up output low voltage[5]	V_{CC} = 3.6 V; I_O = 1 mA; V_I = GND or V_{CC}			0.13	0.55	V
I_I	Input leakage current	V_{CC} = 3.6 V; V_I = V_{CC} or GND	Control pins		±0.1	±1	µA
		V_{CC} = 0 or 3.6 V; V_I = 5.5 V			1	10	
		V_{CC} = 3.6 V; V_I = 5.5 V	I/O Data pins[4]		1	20	
		V_{CC} = 3.6 V; V_I = V_{CC}			0.1	1	
		V_{CC} = 3.6 V; V_I = 0			–1	-5	
I_{OFF}	Output off current	V_{CC} = 0 V; V_I or V_O = 0 to 4.5 V			1	±100	µA
I_{HOLD}	Bus Hold current A or B ports	V_{CC} = 3 V; V_I = 0.8 V		75	150		µA
		V_{CC} = 3 V; V_I = 2.0 V		–75	–150		
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V_O = 5.5 V; V_{CC} = 3.0 V			60	125	µA
$I_{PU/PD}$	Power up/down 3-State output current[3]	$V_{CC} \leq$ 1.2 V; V_O = 0.5 V to V_{CC}; V_I = GND or V_{CC}; $\overline{OE}$/OE = Don't care			15	±100	µA
I_{CCH}	Quiescent supply current	V_{CC} = 3.6 V; Outputs High, V_I = GND or V_{CC}, I_O = 0			0.13	0.19	mA
I_{CCL}		V_{CC} = 3.6 V; Outputs Low, V_I = GND or V_{CC}, I_O = 0			3	12	
I_{CCZ}		V_{CC} = 3.6 V; Outputs Disabled; V_I = GND or V_{CC}, I_O = 0			0.13	0.19	
ΔI_{CC}	Additional supply current per input pin[2]	V_{CC} = 3 V to 3.6 V; One input at V_{CC} -0.6 V, Other inputs at V_{CC} or GND			0.1	0.2	mA

NOTES:
1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2 V to V_{CC} = 3.3 V ± 0.3 V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
4. Unused pins at V_{CC} or GND.
5. For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.

AC CHARACTERISTICS

GND = 0 V, $t_R = t_F$ = 2.5 ns, C_L = 50 pF, R_L = 500 Ω; T_{amb} = –40°C to +85°C.

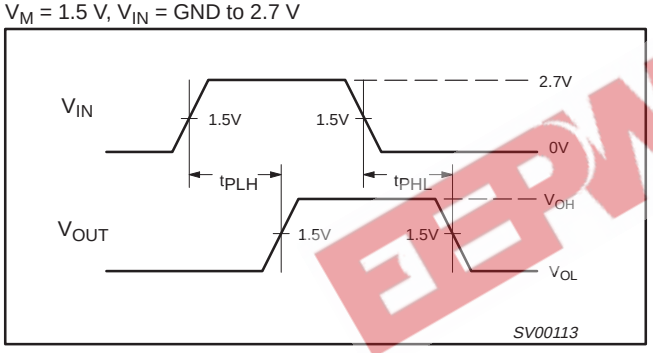
SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			V_{CC} = 3.3 V ±0.3 V			V_{CC} = 2.7 V	
			MIN	TYP[1]	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay An to Bn, Bn to An	1	1.0 1.0	2.3 2.5	3.5 3.7	4.3 4.1	ns
t_{PZH} t_{PZL}	Output enable time $\overline{OEBA}$ to An	2 3	1.0 1.1	3.7 3.7	5.9 5.9	7.6 6.8	ns
t_{PHZ} t_{PLZ}	Output disable time $\overline{OEBA}$ to An	2 3	1.8 1.8	3.6 3.2	5.0 4.5	5.5 4.6	ns
t_{PZH} t_{PZL}	Output enable time OEAB to Bn	2 3	1.0 1.4	4.2 4.3	6.3 6.2	7.8 6.9	ns
t_{PHZ} t_{PLZ}	Output disable time OEAB to Bn	2 3	2.3 2.0	3.9 3.6	6.1 5.3	6.9 5.8	ns

NOTE:

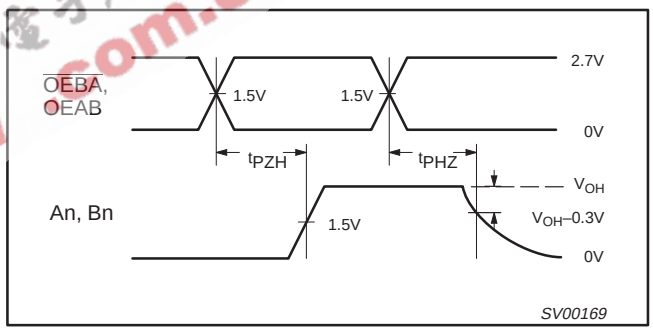
1. All typical values are at V_{CC} = 3.3 V and T_{amb} = 25°C.

AC WAVEFORMS

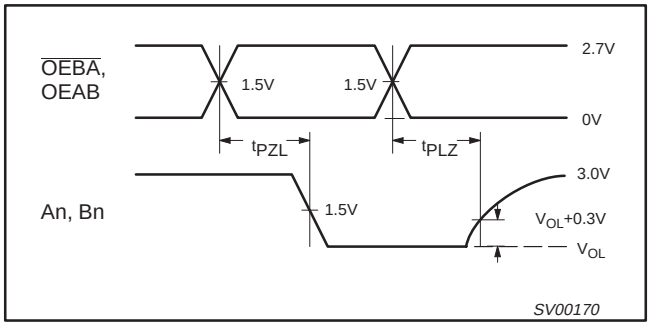
V_M = 1.5 V, V_{IN} = GND to 2.7 V



Waveform 1. Propagation Delay for Non-Inverting Output

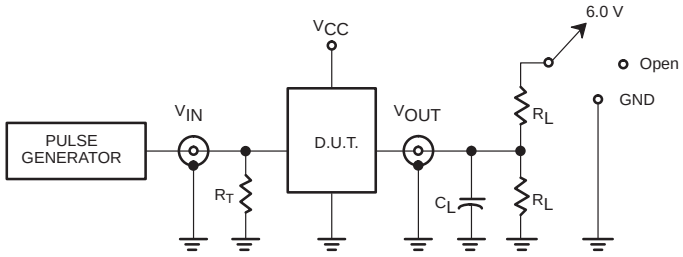


Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level

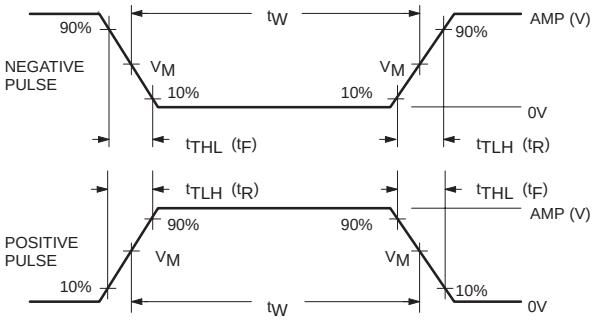


Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORM



Test Circuit for 3-State Outputs



V_M = 1.5 V
Input Pulse Definition

SWITCH POSITION

TEST	SWITCH
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6V
t_{PHZ}/t_{PZH}	GND

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74LVT	2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	≤ 2.5 ns

DEFINITIONS

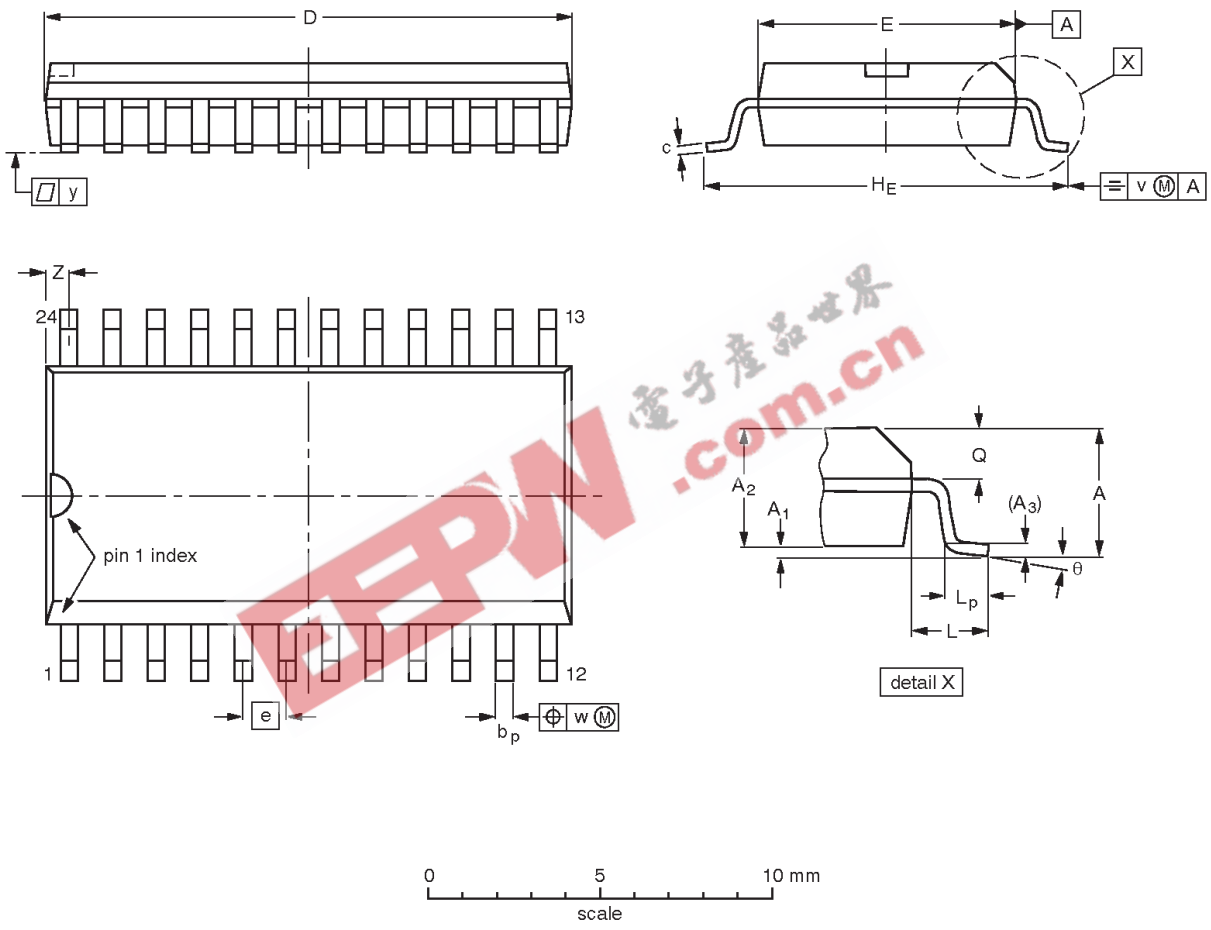
R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SV00092

SO24: plastic small outline package; 24 leads; body width 7.5 mm **SOT137-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

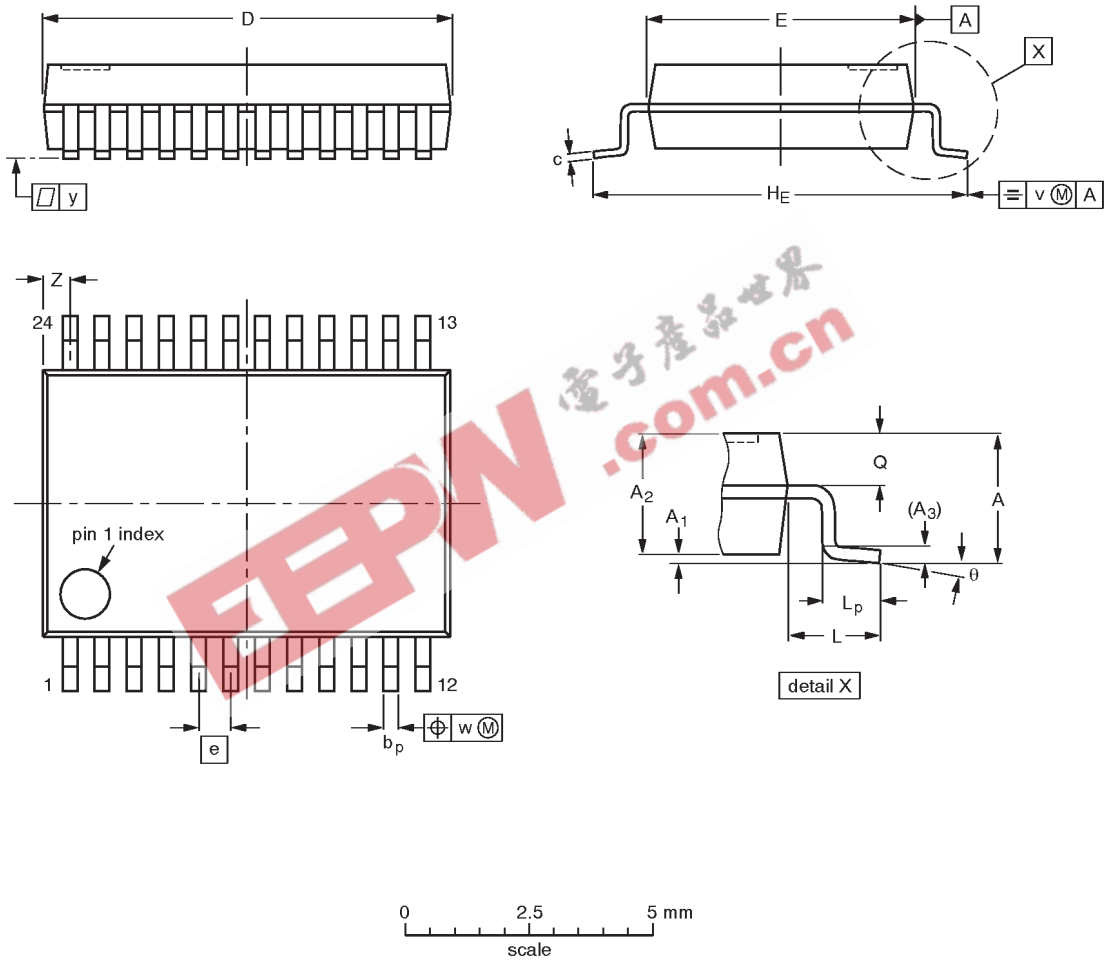
UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8^o 0^o
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT137-1	075E05	MS-013AD				~~95-01-24~~ 97-05-22

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm **SOT340-1**



DIMENSIONS (mm are the original dimensions)

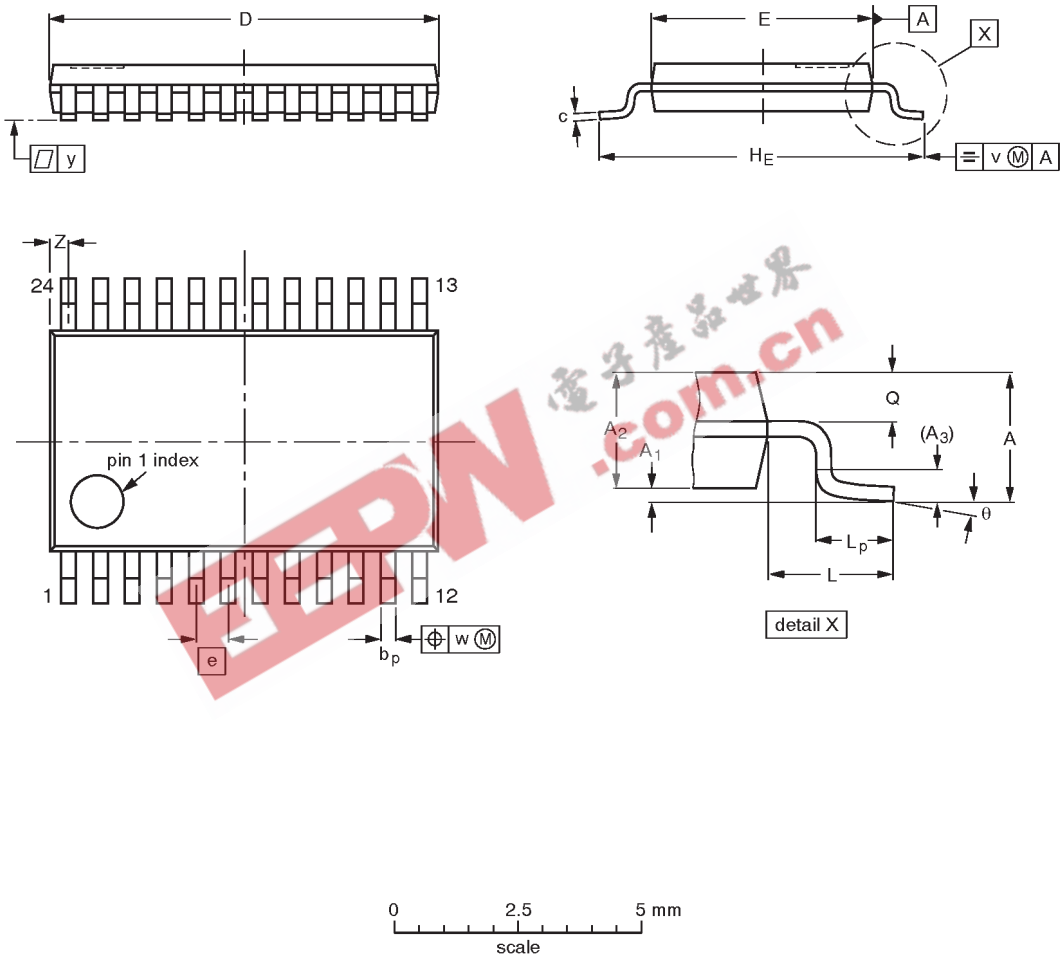
UNIT	A max.	A_1	A_2	A_3	b_p	c	D(1)	E(1)	e	H_E	L	L_p	Q	v	w	y	Z(1)	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT340-1		MO-150AG				~~93-09-08~~ 95-02-04

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm **SOT355-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT355-1		MO-153AD				~~93-06-16~~ 95-02-04

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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